

Please choose the best answer for the following 9 questions and fill the table (Show your calculations).

1	2	3	4	5	6	7	8	9
B	C	E	A	B	B	B	B	D

3 x 2.5

Q1 Cadmium sulfide has a band gap of 1.85 eV. Find maximum wavelength for resistance change by photon absorption. Note that $1 \text{ eV} = 1.6 \times 10^{-19} \text{ J}$, Planck's constant $h = 6.63 \times 10^{-34} \text{ J.s}$, speed of light $c = 3 \times 10^8 \text{ m/s}$

$$\lambda_{\max} = \frac{hc}{\Delta E_{\text{gap}}} (E_{\text{gap}}) \Rightarrow \frac{6.63 \times 10^{-34} \times 3 \times 10^8}{1.85 \times 1.6 \times 10^{-19}}$$

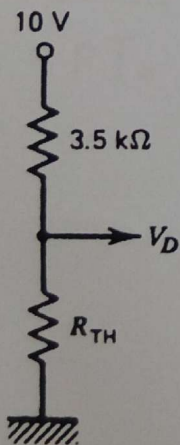
- A) 510 nm B) 672 nm C) 691 nm D) 734 nm E) 762 nm

Q2 Adding impurities to semiconducting material in photodiode sensors will:

- A) Increase series resistance B) Narrow depletion region
 C) Make the device faster D) A+C E) B+C



Q3 A thermistor has a $3.5 \text{ k}\Omega$ resistance at 20°C . The dissipation constant is $P_D = 30 \text{ mW}/^\circ\text{C}$. The sensor is used in the following circuit to provide 5 V at 20°C . Evaluate the error from self-heating in $^\circ\text{C}$



- A) 0.185 B) 0.201 C) 0.238 D) 0.255 E) 0.313

Q4 Compared with thermistors a platinum RTD has lower :

- A) Sensitivity B) predictability C) linearity
D) Temperature range E) Non of the above

Q5 The table for J type thermocouple is attached. Find the output voltage if the sensor is measuring a temperature of 114 °C with a reference of 25 °C: (mV)

$V_o = ?$

- A) 3.258 B) 3.706 C) 3.813 D) 4.020 E) 4.755

Q6 For Q5, the sensitivity of this sensor at 110°C is (V/°C)



$$\text{Sensitivity} = \frac{\Delta V}{\Delta T}$$

- A) 0.054 B) 0.064 C) 0.074 D) 0.084 E) 0.094

Q7 A photovoltaic cell is to be used with radiation of intensity from 5 to 12 mw/cm². Its unloaded output voltage ranges from 0.22 to 0.41 V over this intensity while it delivers current from 0.5 mA to 1.7 mA into a 150 Ω load. The short circuit current range is (mA):

$$I_{sc} = P I_o$$

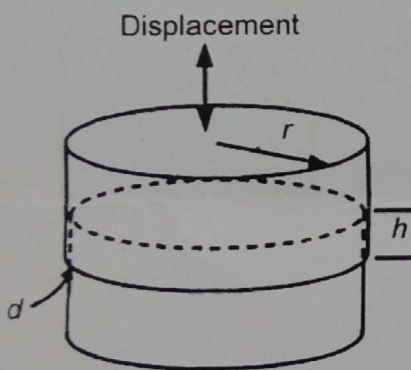
- A) 0.875 - 10.133 B) 0.890 - 9.795 C) 0.801 - 8.133
D) 0.758 - 4.497 E) 0.705 - 4.315

Q8 for Q7, If the unloaded output voltage ranges from 0.3 to 0.6 V, and short circuit current range from 0.5 to 1.5 mA. The optimum value for load resistor when the cell is used as a generator is: (Ω)

- A) 123 B) 147 C) 215 D) 295 E) 344

Q9 Figure below shows a capacitive-displacement sensor. The two metal cylinders are separated by a plastic sheath of thickness 1 mm and dielectric constant of 3. If the radius is 2.5 cm, find the sensitivity in pF/m as the upper part slides in and out of the lower cylinder. (note that air permittivity is 8.85 pF/m)

- A) 2085 B) 2780 C) 3475 **D) 4170** E) 4865



$$C = \frac{\epsilon_r \epsilon_0 R \pi}{D}$$

$$\Rightarrow \frac{dC}{dH} = \frac{2 \epsilon_r \epsilon_0 R \pi}{D}$$

$$= \frac{2 * 8.85 * 10^{-12} * 2.5 * 10^{-2} * \pi}{1 * 10^{-3}}$$

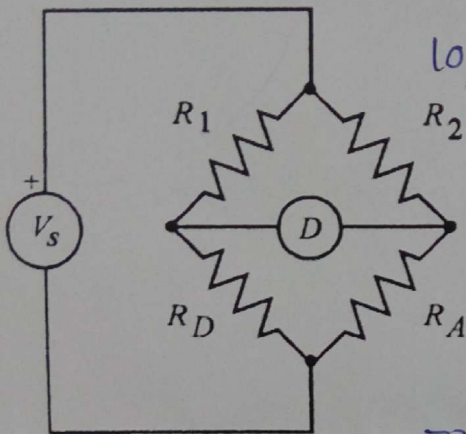


A strain gage with gage factor $G=2.03$. The gage is connected in an equal arms bridge where all resistors equal 250Ω as shown below (where R_A is the active strain gage). If $V_S=10 \text{ V}$, Solve questions 10, 11, and 12.

Q10) what is the detector voltage if a strain of 1 mm/m is applied.

Q11) If a raise in temperature increased only the strain gage resistor R_A by 1Ω (R_1 , R_2 , and R_D are not affected by this temperature). Find the percentage error for the 1 mm/m strain in Q10.

Q12) If R_D is a dummy gage and it is affected by temperature as R_A resolve Q11.



10)

$$V_{th} = \frac{V_S \left(-\frac{\Delta R}{R} \right)}{(1+n)^2}$$

$$\Rightarrow V_{th} = 10 \left(\right)$$

$$\Rightarrow \frac{\Delta R}{R} = G \cdot \epsilon \Rightarrow 2.03 \times$$

$$\Rightarrow \frac{10 \left(\frac{\Delta R}{R} \right)}{(1+1)^2}$$

$$\Rightarrow \frac{-\Delta}{R} = G$$

$$\textcircled{2} E_r = U$$

